DCR690G52

Phase Control Thyristor

Replaces DS5830-3 DS5830-4 August 2014 (LN31837)

FEATURES

- Double Side Cooling
- High Surge Capability

APPLICATIONS

- High Power Drives
- High Voltage Power Supplies
- Static Switches

VOLTAGE RATINGS

Part and Ordering Number	Repetitive Peak Voltages V_{DRM} and V_{RRM} V	Conditions
DCR690G52* DCR690G50 DCR690G48	5200 5000 4800	T_{vj} = -40°C to 125°C, I_{DRM} = I_{RRM} = 100mA, V_{DRM}, V_{RRM} t_p = 10ms, V_{DSM} & V_{RSM} = V_{DRM} & V_{RRM} + 100V respectively

Lower voltage grades available.
* 5000V @ -40^0 C, 5200V @ 0^0 C

ORDERING INFORMATION

When ordering, select the required part number shown in the Voltage Ratings selection table.

For example:

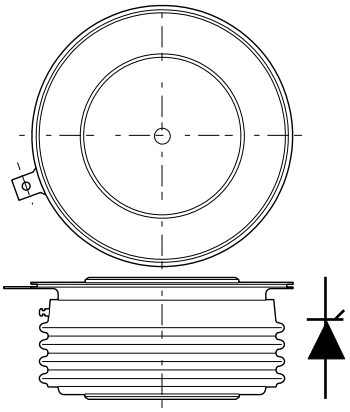
DCR690G52

Note: Please use the complete part number when ordering and quote this number in any future correspondence relating to your order.

KEY PARAMETERS

V_{DRM}	5200V
$I_{T(AV)}$	690A
I_{TSM}	9450A
dV/dt*	1500V/µs
dI/dt	300A/us

*** Higher dV/dt selections available**



Outline type code: G

(See Package Details for further information)

Fig. 1 Package outline

CURRENT RATINGS

T_{case} = 60°C unless stated otherwise

Symbol	Parameter	Test Conditions	Max.	Units
Double Side Cooled				
$I_{T(AV)}$	Mean on-state current	Half wave resistive load	690	A
$I_{T(RMS)}$	RMS value	-	1084	A
I_T	Continuous (direct) on-state current	-	1050	A

SURGE RATINGS

Symbol	Parameter	Test Conditions	Max.	Units
I_{TSM}	Surge (non-repetitive) on-state current	10ms half sine, T_{case} = 125°C	9.45	kA
I^2t	I^2t for fusing	V_R = 0	0.45	MA^2s

THERMAL AND MECHANICAL RATINGS

Symbol	Parameter	Test Conditions		Min.	Max.	Units
$R_{th(j-c)}$	Thermal resistance – junction to case	Double side cooled	DC	-	0.0268	°C/W
		Single side cooled	Anode DC	-	0.0527	°C/W
			Cathode DC	-	0.0652	°C/W
$R_{th(c-h)}$	Thermal resistance – case to heatsink	Clamping force 11.5kN	Double side	-	0.0072	°C/W
		(with mounting compound)	Single side	-	.0144	°C/W
T_{vj}	Virtual junction temperature	Blocking V_{DRM} / V_{RRM}		-	125	°C
T_{stg}	Storage temperature range			-55	125	°C
F_m	Clamping force			10	13	kN

DYNAMIC CHARACTERISTICS

Symbol	Parameter	Test Conditions		Min.	Max.	Units
I_{RRM}/I_{DRM}	Peak reverse and off-state current	At V_{RRM}/V_{DRM}, T_{case} = 125°C		-	100	mA
dV/dt	Max. linear rate of rise of off-state voltage	To 67% V_{DRM}, T_j = 125°C, gate open		-	1500	V/µs
dI/dt	Rate of rise of on-state current	From 67% V_{DRM} to 2x $I_{T(AV)}$	Repetitive 50Hz	-	150	A/µs
		Gate source 30V, 10Ω, t_r < 0.5µs, T_j = 125°C	Non-repetitive	-	300	A/µs
$V_{T(TO)}$	Threshold voltage – Low level	100A to 380A at T_{case} = 125°C		-	.9	V
	Threshold voltage – High level	380A to 3000A at T_{case} = 125°C		-	1.075	V
r_T	On-state slope resistance – Low level	100A to 380A at T_{case} = 125°C		-	1.618	mΩ
	On-state slope resistance – High level	380A to 3000A at T_{case} = 125°C		-	1.125	mΩ
t_{gd}	Delay time	V_D = 67% V_{DRM}, gate source 30V, 10Ω t_r = 0.5µs, T_j = 25°C		-	3	µs
t_q	Turn-off time	T_j = 125°C, V_R = 200V, dI/dt = 5A/µs, dV_{DR}/dt = 20V/µs linear		400	800	µs
Q_S	Stored charge	I_T = 2000A, T_j = 125°C, dI/dt = 5A/µs,		1200	2400	µC
I_L	Latching current	T_j = 25°C, V_D = 5V		-	3	A
I_H	Holding current	T_j = 25°C, R_{G-K} = ∞, I_{TM} = 500A, I_T = 5A		-	300	mA

GATE TRIGGER CHARACTERISTICS AND RATINGS

Symbol	Parameter	Test Conditions	Max.	Units
V_{GT}	Gate trigger voltage	V_{DRM} = 5V, T_{case} = 25°C	1.5	V
V_{GD}	Gate non-trigger voltage	At 50% V_{DRM}, T_{case} = 125°C	0.4	V
I_{GT}	Gate trigger current	V_{DRM} = 5V, T_{case} = 25°C	350	mA
I_{GD}	Gate non-trigger current	At 50% V_{DRM}, T_{case} = 125°C	10	mA

CURVES

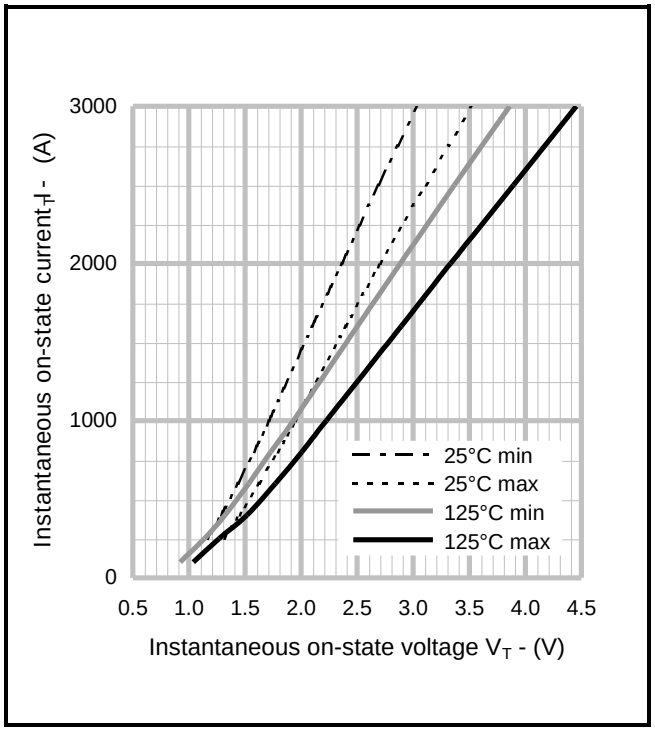


Fig.2 Maximum & minimum on-state characteristics

V_{TM} EQUATION

$V_{TM} = A + B\ln(I_T) + C.I_T + D.\sqrt{I_T}$

Where A = 0.246536
B = 0.166331
C = 0.001110
D = -0.008349

these values are valid for T_j = 125°C for I_T 50A to 3000A

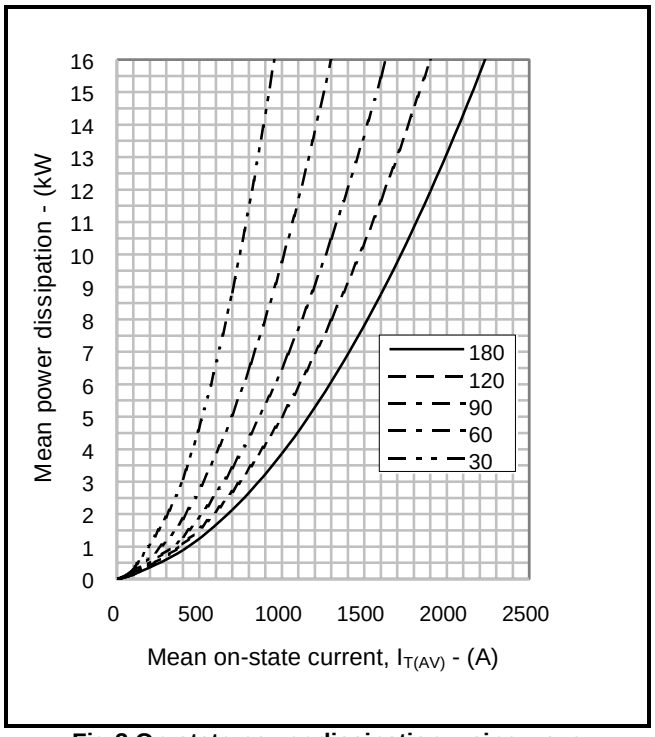


Fig.3 On-state power dissipation – sine wave

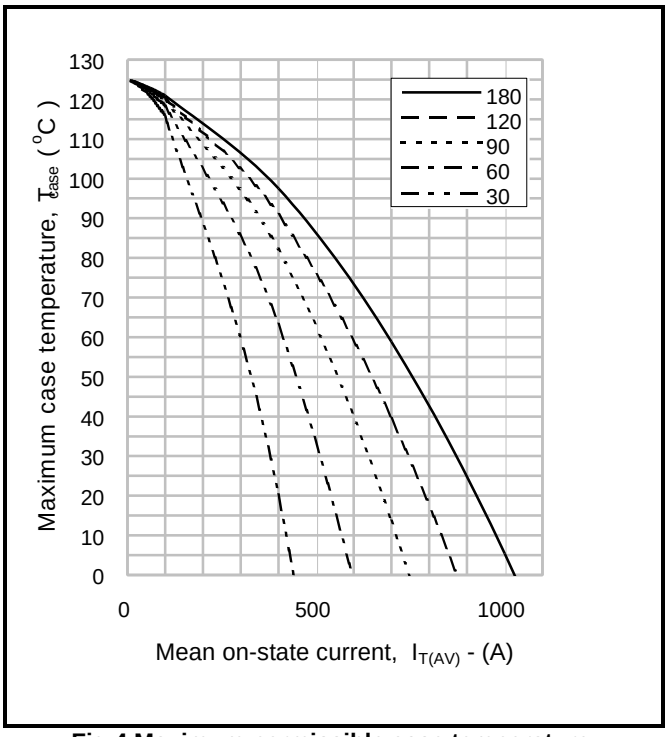


Fig.4 Maximum permissible case temperature, double side cooled – sine wave

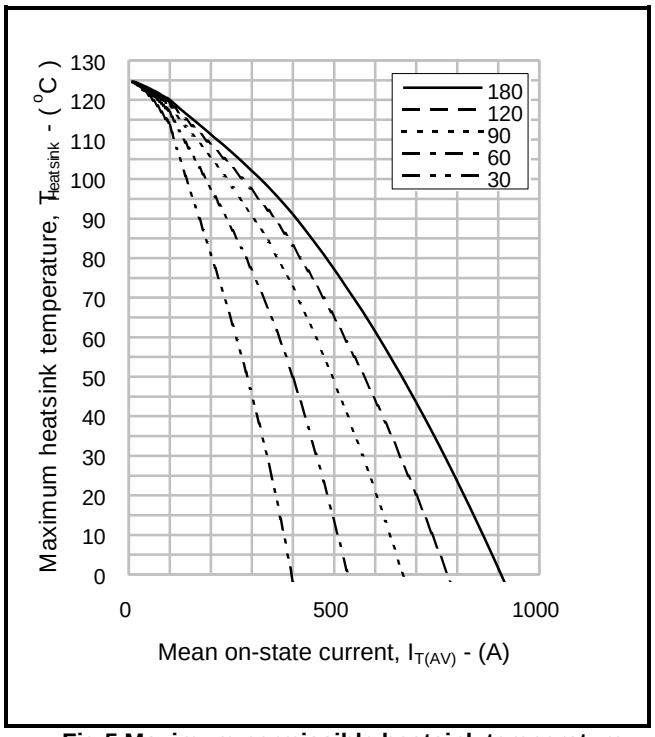


Fig.5 Maximum permissible heatsink temperature, double side cooled – sine wave

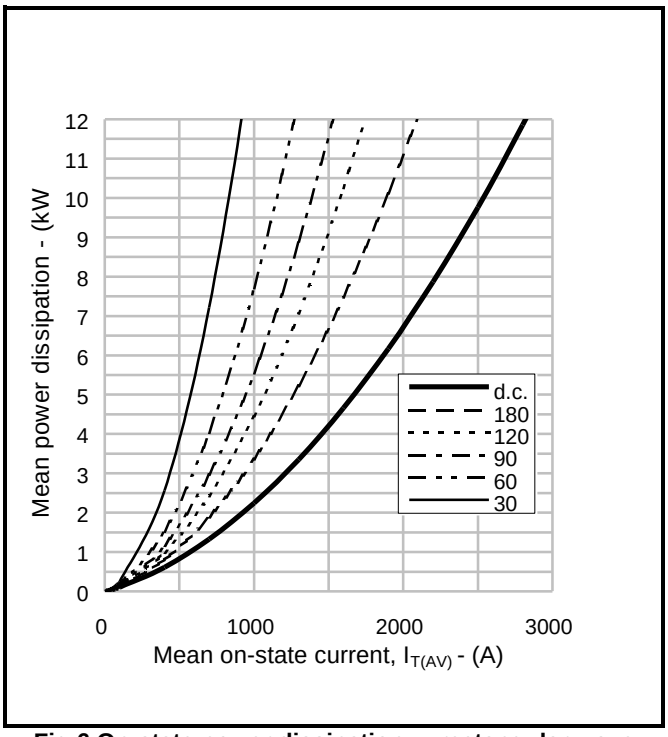


Fig.6 On-state power dissipation – rectangular wave

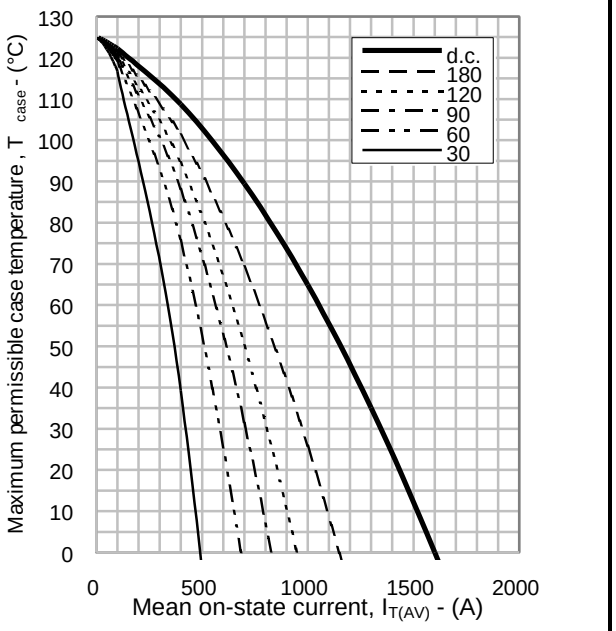


Fig.7 Maximum permissible case temperature, double side cooled – rectangular wave

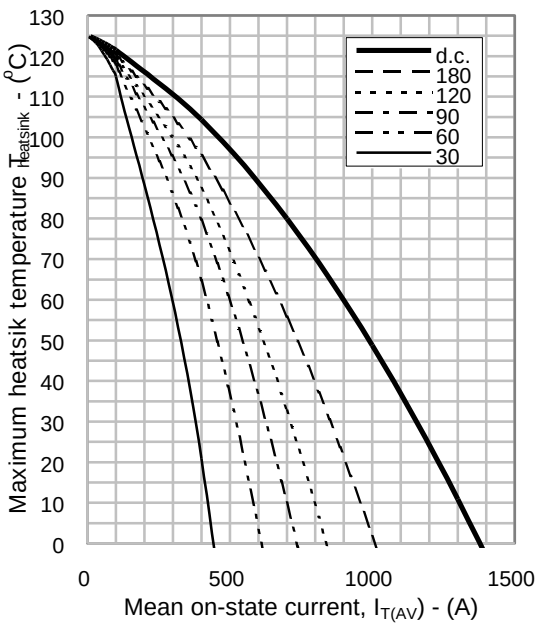
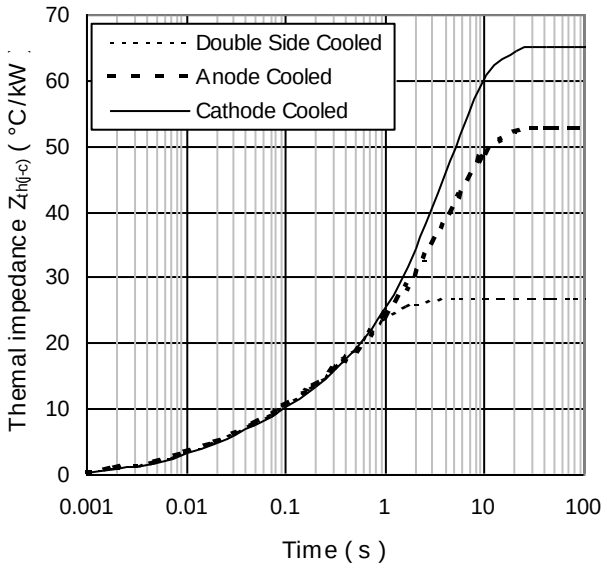


Fig.8 Maximum permissible heatsink temperature, double side cooled – rectangular wave



		1	2	3	4
Double side cooled	R_i (°C/kW)	2.2995	5.4226	16.9074	2.1488
	T_i (s)	0.0066401	0.0457025	0.4962482	1.8248
Anode side cooled	R_i (°C/kW)	2.3214	5.2661	10.2686	34.8031
	T_i (s)	0.0066948	0.045528	0.3484209	4.582
Cathode side cooled	R_i (°C/kW)	2.4895	5.9105	7.4256	49.3432
	T_i (s)	0.0070404	0.052895	0.3933903	4.2295

$Z_{th} = \sum [R_i \times (1\text{-exp. } (t/t_i))]$ **[1]**

$\Delta R_{th(j-c)}$ Conduction

Tables show the increments of thermal resistance $R_{th(j-c)}$ when the device operates at conduction angles other than d.c.

Double side cooling		
	ΔZ_{th} (z)	
θ°	sine.	rect.
180	4.15	2.72
120	4.90	4.02
90	5.74	4.79
60	6.53	5.65
30	7.16	6.64
15	7.46	7.18

Anode Side Cooling		
	ΔZ_{th} (z)	
θ°	sine.	rect.
180	4.15	2.72
120	4.89	4.02
90	5.73	4.78
60	6.52	5.65
30	7.15	6.62
15	7.44	7.16

Cathode Sided Cooling		
	ΔZ_{th} (z)	
θ°	sine.	rect.
180	4.13	2.71
120	4.87	4.00
90	5.69	4.76
60	6.46	5.60
30	7.07	6.56
15	7.36	7.09

Fig.9 Maximum (limit) transient thermal impedance – junction to case (°C/kW)

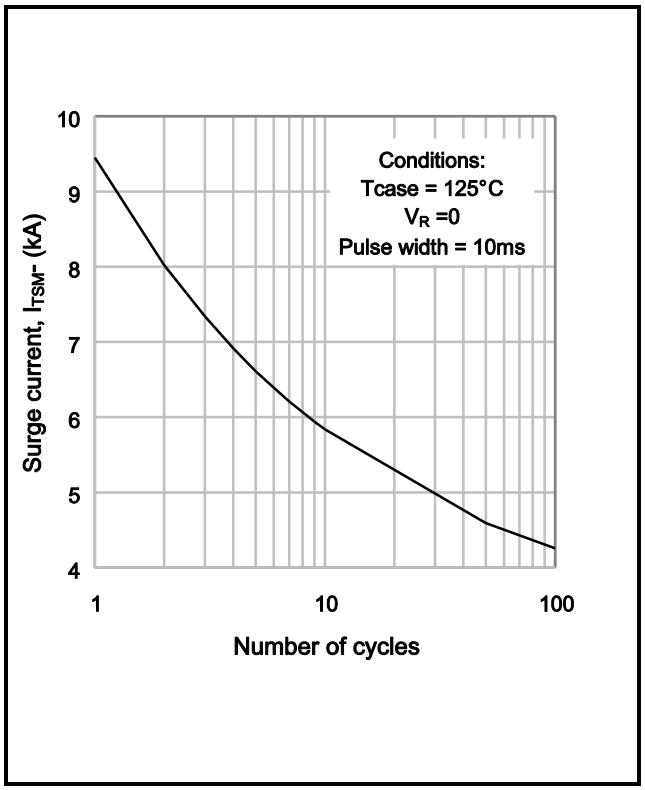


Fig.10 Multi-cycle surge current

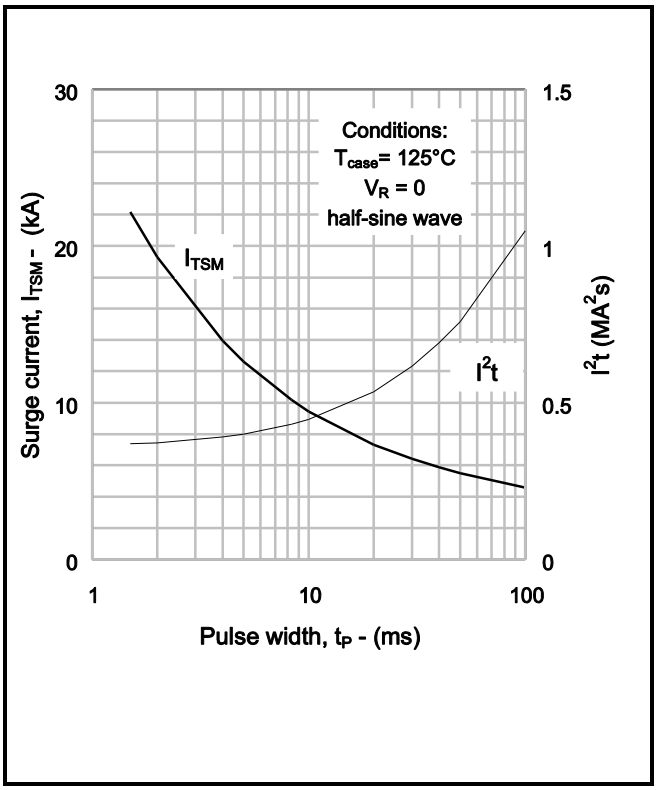


Fig.11 Single-cycle surge current

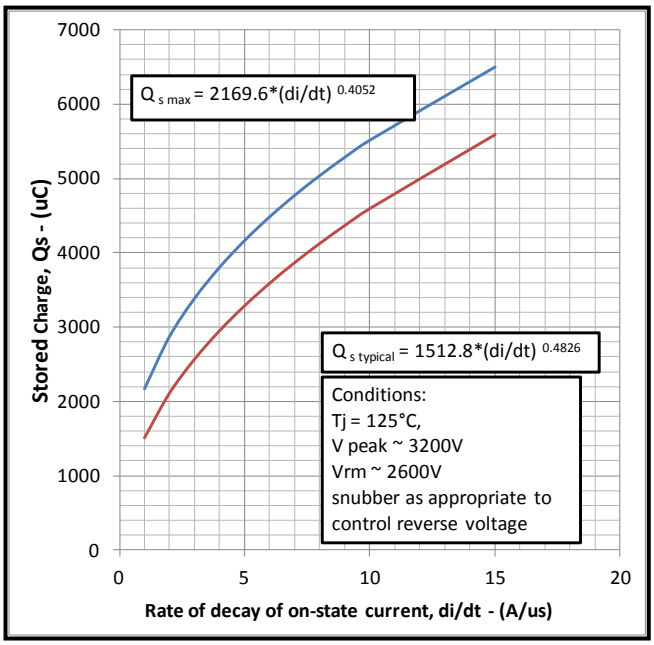


Fig.12 Stored charge vs dI/dt

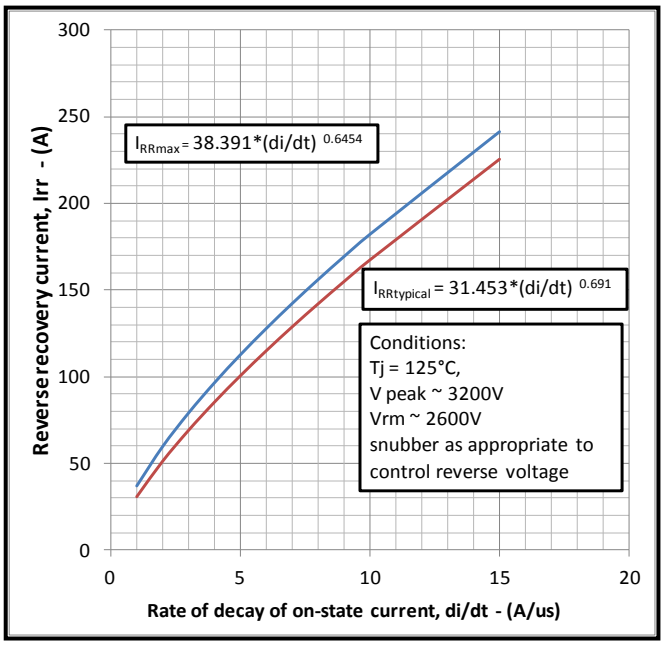


Fig.13 Reverse recovery current vs dI/dt

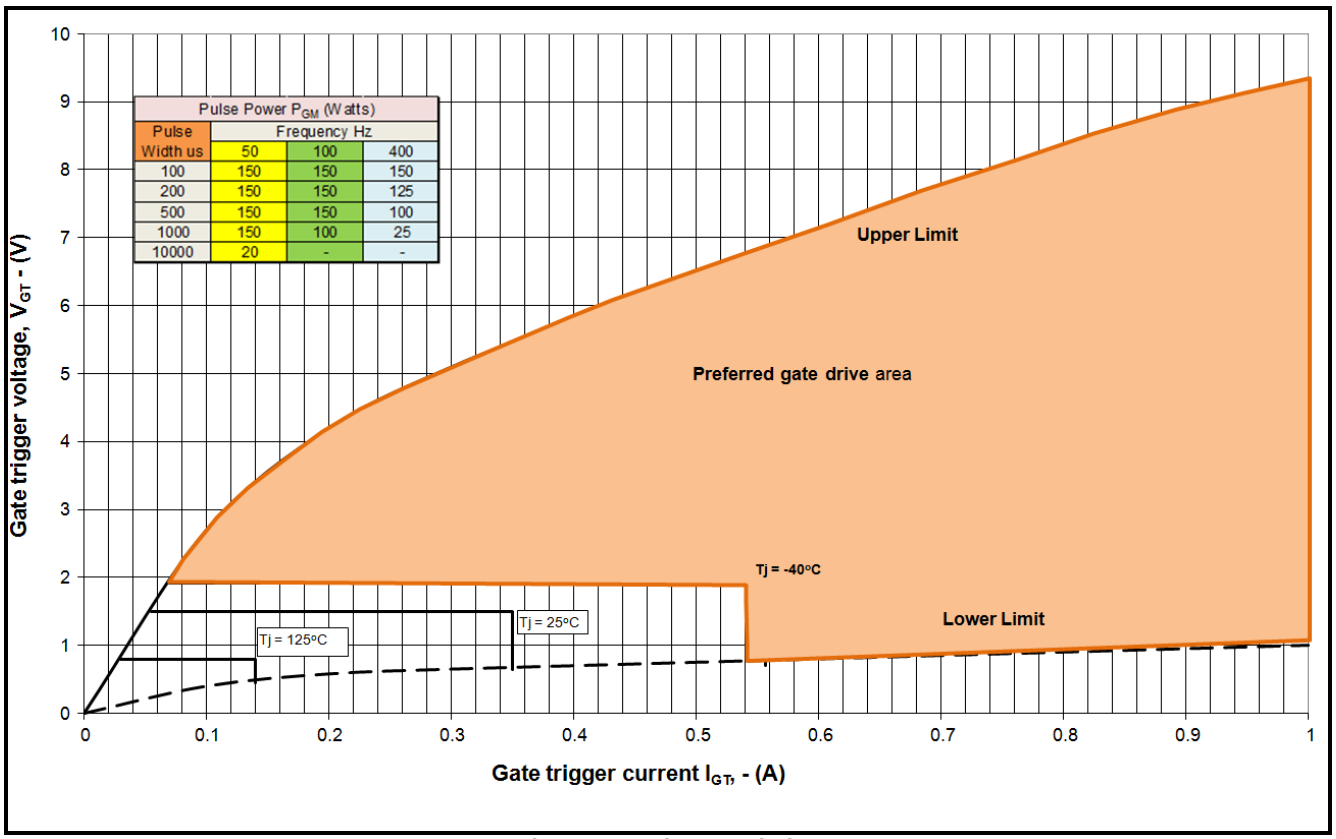


Fig14 Gate Characteristics

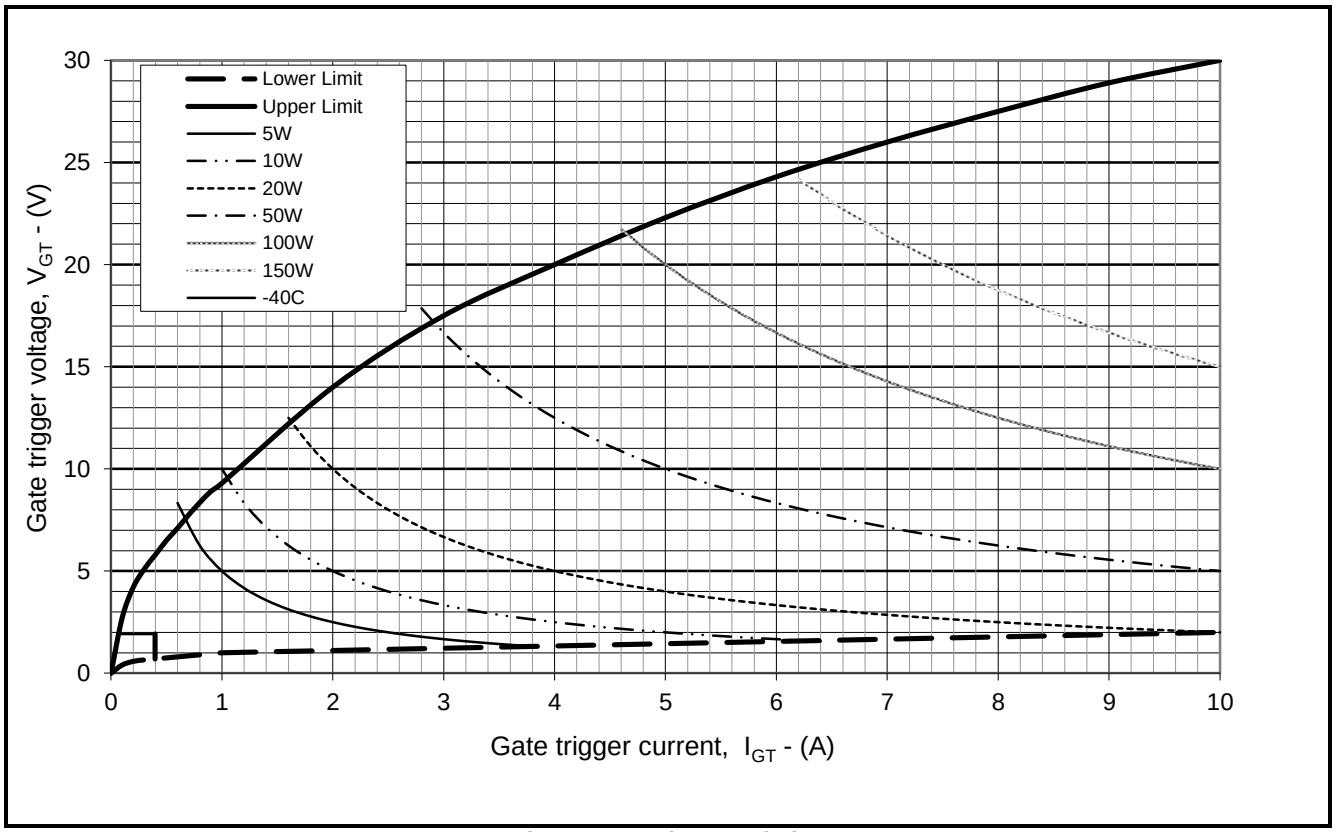
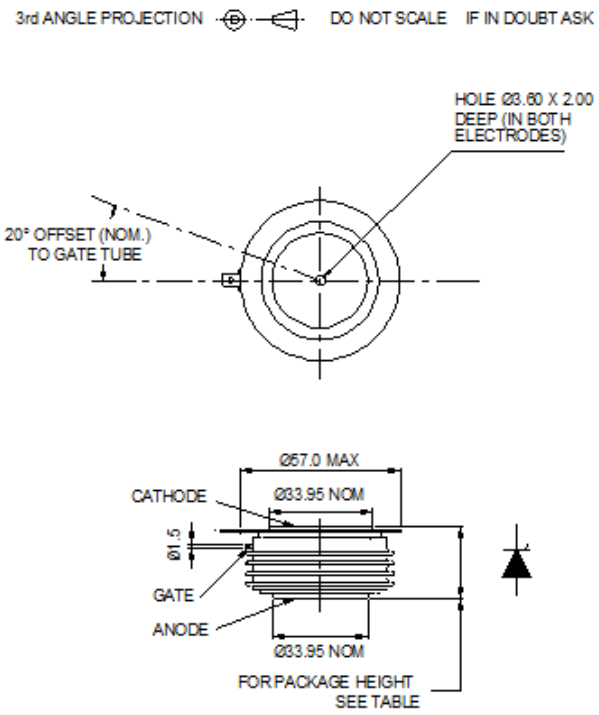


Fig. 15 Gate characteristics

PACKAGE DETAILS

For further package information, please contact Customer Services. All dimensions in mm, unless stated otherwise. DO NOT SCALE.



Device	Maximum Thickness (mm)	Minimum Thickness (mm)
DCR803SG18	26.415	25.865
DCR806SG28	26.49	25.94
DCR818SG48	26.84	26.17
DCR820SG65	27.1	26.55
DCR1080G22	26.415	25.865
DCR960G28	26.49	25.94
DCR780G42	26.72	26.17
DCR690G52	**26.84**	**26.29**
DCR590G65	27.1	26.55
DCR470G85	27.46	26.91

Clamping force: 11.5 kN ±10%
Lead length: 420mm
Lead terminal connector: M4 ring

Package outline type code: G

Fig.16 Package outline

IMPORTANT INFORMATION:
This publication is provided for information only and not for resale.
The products and information in this publication are intended for use by appropriately trained technical personnel.

Due to the diversity of product applications, the information contained herein is provided as a general guide only and does not constitute any guarantee of suitability for use in a specific application.The user must evaluate the suitability of the product and the completeness of the product data for the application. The user is responsible for product selection and ensuring all safety and any warning requirements are met. Should additional product information be needed please contact Customer Service.

Although we have endeavoured to carefully compile the information in this publication it may contain inaccuracies or typographical errors. The information is provided without any warranty or guarantee of any kind.
This publication is an uncontrolled document and is subject to change without notice. When referring to it please ensure that it is the most up to date version and has not been superseded.

The products are not intended for use in applications where a failure or malfunction may cause loss of life, injury or damage to property. The user must ensure that appropriate safety precautions are taken to prevent or mitigate the consequences of a product failure or malfunction.

The products must not be touched when operating because there is a danger of electrocution or severe burning. Always use protective safety equipment such as appropriate shields for the product and wear safety glasses. Even when disconnected any electric charge remaining in the product must be discharged and allowed to cool before safe handling using protective gloves.

Extended exposure to conditions outside the product ratings may affect reliability leading to premature product failure. Use outside the product ratings is likely to cause permanent damage to the product. In extreme conditions, as with all semiconductors, this may include potentially hazardous rupture, a large current to flow or high voltage arcing, resulting in fire or explosion. Appropriate application design and safety precautions should always be followed to protect persons and property.

Product Status & Product Ordering:

We annotate datasheets in the top right hand corner of the front page, to indicate product status if it is not yet fully approved for production. The annotations are as follows:-

Target Information:	This is the most tentative form of information and represents a very preliminary specification. No actual design work on the product has been started.
Provisional Information:	Some initial development work has been performed. The datasheet represents a view of the end product based on very limited information. Certain details will change.
Preliminary Information:	The product design is complete and final characterisation for volume production is in progress.The datasheet represents the product as it is now understood but details may change.
No Annotation:	The product has been approved for production and unless otherwise notified by Dynex any product ordered will be supplied to the **current version of the data sheet prevailing at the time of our order acknowledgement.**

All products and materials are sold and services provided subject to Dynex's conditions of sale, which are available on request.
Any brand names and product names used in this publication are trademarks, registered trademarks or trade names of their respective owners.

HEADQUARTERS OPERATIONS
DYNEX SEMICONDUCTOR LIMITED
Doddington Road, Lincoln, Lincolnshire, LN6 3LF
United Kingdom.
Phone: +44 (0) 1522 500500
Web: http://www.dynexsemi.com

CUSTOMER SERVICE
Phone: +44 (0) 1522 502753 / 502901
e-mail: powersolutions@dynexsemi.com